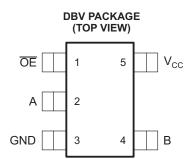


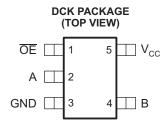
FEATURES

- Output Voltage Translation Tracks V_{CC}
- Supports Mixed-Mode Signal Operation on All Data I/O Ports
 - 5-V Input Down to 3.3-V Output Level Shift With 3.3-V V_{CC}
 - 5-V/3.3-V Input Down to 2.5-V Output Level Shift With 2.5-V $\rm V_{\rm CC}$
- 5-V-Tolerant I/Os, With Device Powered Up or Powered Down
- Bidirectional Data Flow With Near-Zero
 Propagation Delay
- Low ON-State Resistance (r_{on}) Characteristics (r_{on} = 5 Ω Typ)
- Low Input/Output Capacitance Minimizes Loading (C_{io(OFF)} = 5 pF Typ)
- Data and Control Inputs Provide Undershoot Clamp Diodes

- Low Power Consumption (I_{CC} = 20 μA Max)
- V_{cc} Operating Range From 2.3 V to 3.6 V
- Data I/Os Support 0- to 5-V Signaling Levels (0.8 V, 1.2 V, 1.5 V, 1.8 V, 2.5 V, 3.3 V, 5 V)
- Control Inputs Can Be Driven by TTL or 5-V/3.3-V CMOS Outputs
- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Performance Tested Per JESD 22

 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)
- Supports Digital Applications: Level Translation, USB Interface, Bus Isolation
- Ideal for Low-Power Portable Equipment





See mechanical drawings for dimensions.

DESCRIPTION/ORDERING INFORMATION

The SN74CB3T1G125 is a high-speed TTL-compatible FET bus switch with low ON-state resistance (r_{on}), allowing for minimal propagation delay. The device fully supports mixed-mode signal operation on all data I/O ports by providing voltage translation that tracks V_{CC}. The SN74CB3T1G125 supports systems using 5-V TTL, 3.3-V LVTTL, and 2.5-V CMOS switching standards, as well as user-defined switching levels (see Figure 1).

The SN74CB3T1G125 is a 1-bit bus switch with a single ouput-enable (\overline{OE}) input. When \overline{OE} is low, the bus switch is ON, and the A port is connected to the B port, allowing bidirectional data flow between ports. When \overline{OE} is high, the bus switch is OFF, and a high-impedance state exists between the A and B ports.

ORDERING INFORMATION

| T _A | PACKA | GE ⁽¹⁾ | ORDERABLE PART NUMBER | TOP-SIDE MARKING ⁽²⁾ |
|----------------|--------------------|-------------------|-----------------------|---------------------------------|
| 40°C to 95°C | SOT (SOT-23) – DBV | Reel of 3000 | SN74CB3T1G125DBVR | W25_ |
| –40°C to 85°C | SOT (SC-70) – DCK | Reel of 3000 | SN74CB3T1G125DCKR | WM_ |

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

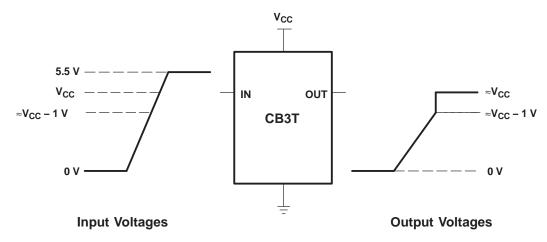
(2) The actual top-side marking has one additional character that designates the assembly/test site.



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DESCRIPTION/ORDERING INFORMATION (CONTINUED)



NOTE A: If the input high voltage (V_{IH}) level is greater than or equal to $V_{CC} - 1$ V, and less than or equal to 5.5 V, then the output high voltage (V_{OH}) level will be equal to approximately the V_{CC} voltage level.

Figure 1. Typical DC Voltage Translation Characteristics

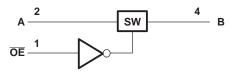
This device is fully specified for partial-power-down applications using I_{off} . The I_{off} feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

FUNCTION TABLE

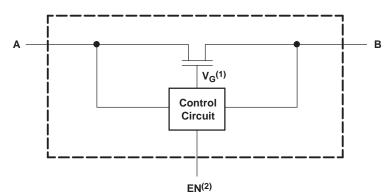
| | INPUT/OUTPUT A | FUNCTION |
|---|-------------------|-----------------|
| L | В | A port = B port |
| н | Z | Disconnect |

LOGIC DIAGRAM (POSITIVE LOGIC)



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SIMPLIFIED SCHEMATIC, EACH FET SWITCH (SW)



(1) Gate voltage (V_G) is equal to approximately V_{CC} + V_T when the switch is ON and $V_I > V_{CC} + V_T$. (2) EN is the internal enable signal applied to the switch.

Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

| | | | MIN | MAX | UNIT |
|-------------------|---|----------------------|------|------|------|
| V _{CC} | Supply voltage range | | -0.5 | 7 | V |
| V _{IN} | Control input voltage range ⁽²⁾⁽³⁾ | | -0.5 | 7 | V |
| V _{I/O} | Switch I/O voltage range ⁽²⁾⁽³⁾⁽⁴⁾ | | -0.5 | 7 | V |
| I _{IK} | Control input clamp current | V _{IN} < 0 | | -50 | mA |
| I _{I/OK} | I/O port clamp current | V _{I/O} < 0 | | -50 | mA |
| I _{IO} | ON-state switch current ⁽⁵⁾ | | | ±128 | mA |
| | Continuous current through V_{CC} or GND | | | ±100 | mA |
| 0 | Deckage thermal impedance (6) | DBV package | | 206 | °C/W |
| θ_{JA} | Package thermal impedance ⁽⁶⁾ | DCK package | | | 0/11 |
| T _{stg} | Storage temperature range | | -65 | 150 | °C |

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings (1) only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

All voltages are with respect to ground, unless otherwise specified. (2)

(3) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

(4) V_I and V_O are used to denote specific conditions for $V_{I/O}$.

(5)

 I_{I} and I_{O} are used to denote specific conditions for $I_{I/O}$. The package thermal impedance is calculated in accordance with JESD 51-7. (6)

Recommended Operating Conditions⁽¹⁾

| | | | MIN | MAX | UNIT |
|------------------|---|---------------------------|-----|-----|------|
| V_{CC} | Supply voltage | | 2.3 | 3.6 | V |
| V | High lovel control input veltage | V_{CC} = 2.3 V to 2.7 V | 1.7 | 5.5 | V |
| VIH | High-level control input voltage $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ | 2 | 5.5 | v | |
| | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | | 0 | 0.7 | V |
| V _{IL} | Low-level control input voltage V _{CC} = 2.7 V to 3.6 V | | | 0.8 | v |
| V _{I/O} | Data input/output voltage | | 0 | 5.5 | V |
| T _A | Operating free-air temperature | | -40 | 85 | °C |

(1) All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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Electrical Characteristics⁽¹⁾

over recommended operating free-air temperature range (unless otherwise noted)

| PAR | AMETER | TEST CONDITIONS | | MIN | TYP ⁽²⁾ | MAX | UNIT | |
|--------------------------------|----------------|---|--|-----|--------------------|------|------|--|
| V _{IK} | | $V_{CC} = 3 V, I_{I} = -18 mA$ | | | | -1.2 | V | |
| V _{OH} | | See Figure 3 and Figure 4 | | | | | | |
| I _{IN} | Control inputs | V_{CC} = 3.6 V, V_{IN} = 3.6 V to 5.5 V or GND | | | | ±10 | μA | |
| | | V _{CC} = 3.6 V, | $V_{I} = V_{CC} - 0.7 \text{ V} \text{ to } 5.5 \text{ V}$ | | | ±20 | | |
| I _I | | Switch ON, | $V_{\rm I}$ = 0.7 V to $V_{\rm CC}$ – 0.7 V | | | -40 | μA | |
| | | $V_{IN} = V_{CC} \text{ or } GND$ | V _I = 0 to 0.7 V | | | ±5 | | |
| I _{OZ} ⁽³⁾ | | V_{CC} = 3.6 V, V_{O} = 0 to 5.5 V, V_{I} = 0, Switch OFF | | | ±10 | μA | | |
| I _{off} | | $V_{CC} = 0, V_{O} = 0 \text{ to } 5.5 \text{ V}, V_{I} = 0$ | | | 10 | μA | | |
| | | $V_{CC} = 3.6 \text{ V}, I_{UC} = 0,$ | $V_I = V_{CC}$ or GND | | | 20 | | |
| ICC | | Switch ON or OFF , $V_{IN} = V_{CC}$ or GND | V _I = 5.5 V | | 20 | | μA | |
| $\Delta I_{CC}^{(4)}$ | Control inputs | V_{CC} = 3 V to 3.6 V, One input at V_{CC} – 0.6 V, Ot | her inputs at V _{CC} or GND | | | 300 | μΑ | |
| C _{in} | Control inputs | $V_{CC} = 3.3 \text{ V}, V_{IN} = V_{CC} \text{ or GND}$ | | | 3 | | pF | |
| C _{io(OFF)} | | V_{CC} = 3.3 V, $V_{I/O}$ = 5.5 V, 3.3 V, or GND, Switch | OFF, $V_{IN} = V_{CC}$ or GND | | 5 | | pF | |
| | | $V_{CC} = 3.3 V$, Switch ON, | V _{I/O} = 5.5 V or 3.3 V | | 4 | | - 5 | |
| C _{io(ON)} | | $V_{IN} = V_{CC}$ or GND | V _{I/O} = GND | 12 | | pF | | |
| | | $V_{CC} = 2.3 \text{ V}, \text{ TYP at } V_{CC} = 2.5 \text{ V},$ | I _O = 24 mA | | 5 | 8 | | |
| | | $V_{I} = 0$ | I _O = 16 mA | | 5 | 8 | 0 | |
| r _{on} ⁽⁵⁾ | | | I _O = 64 mA | | 5 | 7 | Ω | |
| | | $V_{CC} = 3 V, V_{I} = 0$ | I _O = 32 mA | | 5 | 7 | | |

(1) V_{IN} and I_{IN} refer to control inputs. V_I , V_O , I_I , and I_O refer to data pins. (2) All typical values are at $V_{CC} = 3.3$ V (unless otherwise noted), $T_A = 25^{\circ}$ C. (3) For I/O ports, the parameter I_{OZ} includes the input leakage current.

 (4) This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND.
 (5) Measured by the voltage drop between A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

Switching Characteristics

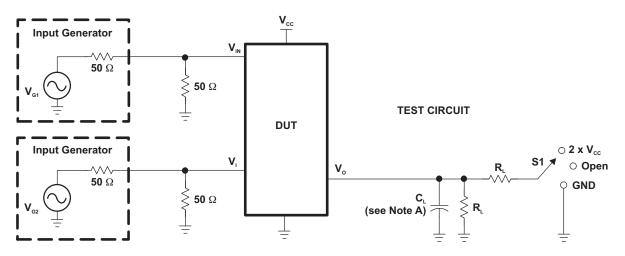
over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | V _{CC} = ± 0.2 | | V _{CC} = 3 ± 0.3 | UNIT | |
|--------------------------------|-----------------|----------------|----------------------------|------|------------------------------|------|----|
| | | (001F01) | MIN | MAX | MIN | MAX | |
| t _{pd} ⁽¹⁾ | A or B | B or A | | 0.15 | | 0.25 | ns |
| t _{en} | ŌĒ | A or B | 1 | 7.5 | 1 | 6.5 | ns |
| t _{dis} | ŌĒ | A or B | 1 | 5.5 | 1 | 6 | ns |

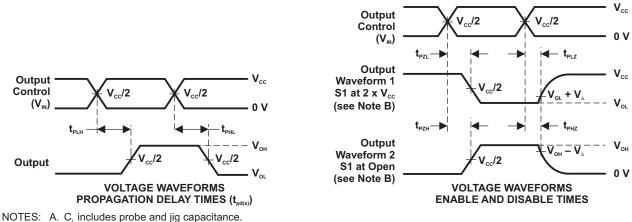
(1) The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

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PARAMETER MEASUREMENT INFORMATION



| TEST | V _{cc} | S1 | R | V, | C _L | V |
|------------------------------------|---|--|------------------------------|------------------------------|-----------------------|------------------|
| t _{pd(s)} | $\begin{array}{c} 2.5 \ V \pm 0.2 \ V \\ 3.3 \ V \pm 0.3 \ V \end{array}$ | Open Open | 500 Ω 500 Ω | 3.6 V or GND 5.5 V or GND | 30 pF 50 pF | |
| t _{PLZ} /t _{PZL} | $\begin{array}{c} 2.5 \ V \pm 0.2 \ V \\ 3.3 \ V \pm 0.3 \ V \end{array}$ | 2 x V _{cc} 2 x V _{cc} | 500 Ω 500 Ω | GND GND | 30 pF 50 pF | 0.15 V 0.15 V |
| t _{PHZ} /t _{PZH} | $\begin{array}{c} 2.5 \ V \pm 0.2 \ V \\ 3.3 \ V \pm 0.3 \ V \end{array}$ | Open Open | 500 Ω 500 Ω | 3.6 V 5.5 V | 30 pF 50 pF | 0.15 V 0.15 V |



- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z₀ = 50 Ω , t \leq 2.5 ns,
- t, ≤ 2.5 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. $t_{_{PZL}}$ and $t_{_{PZH}}$ are the same as $t_{_{en}}$.
- G. t_{PLH} and t_{PHL} are the same as $t_{pd(s)}$. The tpd propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch nd the specified load capacitance, when driven by an ideal voltage source (zero output impedance). H. All parameters and waveforms are not applicable to all devices.

Figure 2. Test Circuit and Voltage Waveforms



TYPICAL CHARACTERISTICS

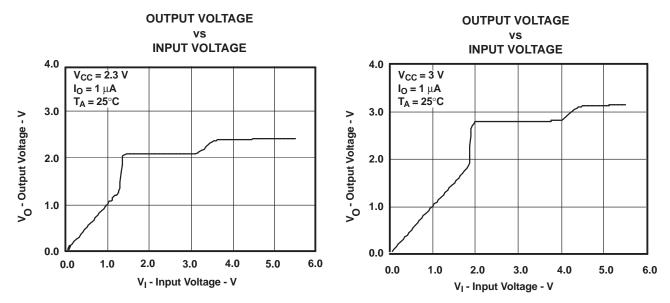


Figure 3. Data Output Voltage vs Data Input Voltage

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TYPICAL CHARACTERISTICS

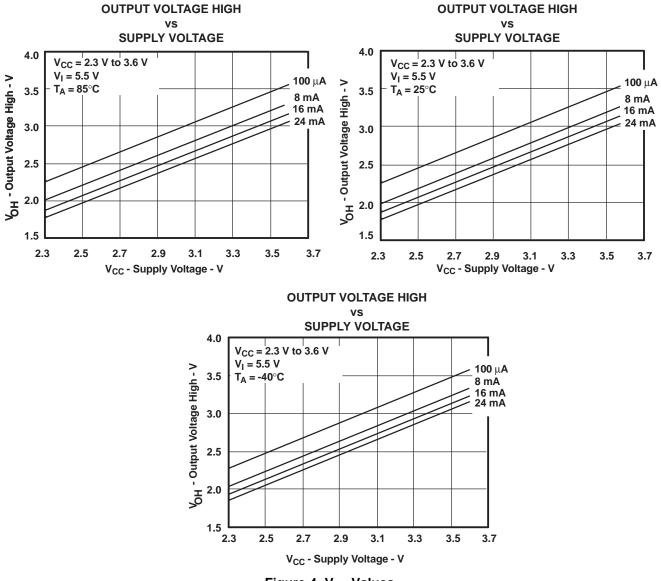


Figure 4. V_{OH} Values



PACKAGING INFORMATION

| Orderable Device | Status ⁽¹⁾ | Package Type | Package Drawing | Pins | Package Qty | Eco Plan ⁽²⁾ | Lead/ Ball Finish | MSL Peak Temp ⁽³⁾ | Samples (Requires Login) |
|-------------------|-----------------------|--------------|--------------------|------|-------------|----------------------------|----------------------|------------------------------|-----------------------------|
| 74CB3T1G125DBVRE4 | ACTIVE | SOT-23 | DBV | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | Add to cart |
| 74CB3T1G125DBVRG4 | ACTIVE | SOT-23 | DBV | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | Add to cart |
| 74CB3T1G125DCKRE4 | ACTIVE | SC70 | DCK | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | Add to cart |
| 74CB3T1G125DCKRG4 | ACTIVE | SC70 | DCK | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | Add to cart |
| SN74CB3T1G125DBVR | ACTIVE | SOT-23 | DBV | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | Add to cart |
| SN74CB3T1G125DCKR | ACTIVE | SC70 | DCK | 5 | 3000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | Add to cart |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION

REEL DIMENSIONS

Texas Instruments





TAPE DIMENSIONS



| A0 | Dimension designed to accommodate the component width |
|----|---|
| B0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

TAPE AND REEL INFORMATION

*All dimensions are nominal

| Device | | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-------------------|--------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| SN74CB3T1G125DBVR | SOT-23 | DBV | 5 | 3000 | 178.0 | 9.0 | 3.23 | 3.17 | 1.37 | 4.0 | 8.0 | Q3 |
| SN74CB3T1G125DBVR | SOT-23 | DBV | 5 | 3000 | 180.0 | 8.4 | 3.23 | 3.17 | 1.37 | 4.0 | 8.0 | Q3 |
| SN74CB3T1G125DCKR | SC70 | DCK | 5 | 3000 | 178.0 | 9.0 | 2.4 | 2.5 | 1.2 | 4.0 | 8.0 | Q3 |

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

30-Jul-2012



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| SN74CB3T1G125DBVR | SOT-23 | DBV | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| SN74CB3T1G125DBVR | SOT-23 | DBV | 5 | 3000 | 202.0 | 201.0 | 28.0 |
| SN74CB3T1G125DCKR | SC70 | DCK | 5 | 3000 | 180.0 | 180.0 | 18.0 |

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

D. Falls within JEDEC MO-178 Variation AA.



DBV (R-PDSO-G5)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.

- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-203 variation AA.



LAND PATTERN DATA



NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



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